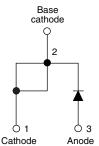
www.vishay.com

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A





PRODUCT SUMMARY				
Package	TO-220FP			
I _{F(AV)}	10 A			
V _R	1000 V, 1200 V			
V _F at I _F	1.33 V			
I _{FSM}	140 A			
t _{rr}	80 ns			
T _J max.	150 °C			
Diode variation	Single die			
Snap factor	0.6			

FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC-JESD47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
V _{RRM}		1000 to 1200	V			
I _{F(AV)}	Sinusoidal waveform	10	٨			
I _{FSM}		140	– A			
t _{rr}	1 A, 100 A/μs	80	ns			
V _F	10 A, T _J = 25 °C	1.33	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4		
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	4		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	$T_{C} = 95 \text{ °C}$, 180° conduction half sine wave	10			
Maximum peak one cycle	I	10 ms sine pulse, rated V _{RRM} applied	115	А		
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	140			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	66	A ² s		
		10 ms sine pulse, no voltage reapplied	94	A-2		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s		

Revision: 18-Jun-13

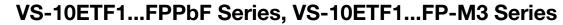
Document Number: 94093

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

1



Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	r _t	T, = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}	1j = 150 C		0.96	V
		T _J = 25 °C		0.1	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V _R = Rated V _{RRM}	4	mA

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Reverse recovery time	t _{rr}	l _F at 10 Apk 25 A/μs 25 ℃	310	ns	I _{FM} t.	
Reverse recovery current	I _{rr}		4.7	А		
Reverse recovery charge	Q _{rr}		1.05	μC	$\frac{\text{dir}}{\text{dt}}$	
Snap factor	S		0.6		I IRM(REC)	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance junction to case		R _{thJC}	DC operation	2.5		
Maximum thermal resistance junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance case to heatsink	9,	R _{thCS}	Mounting surface, smooth and greased	0.5		
Approvimeto weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque maximu	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-220 FULL-PAK	10ETF10FP 10ETF12FP		

Revision: 18-Jun-13 2 Document Number: 94093 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

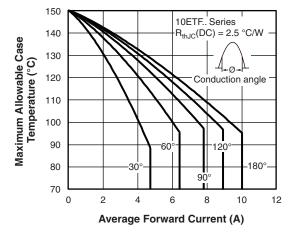


Fig. 1 - Current Rating Characteristics

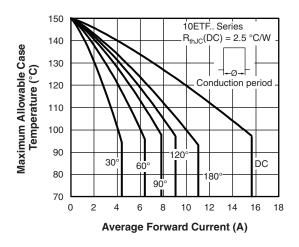


Fig. 2 - Current Rating Characteristics

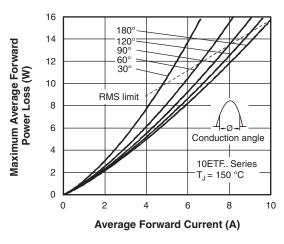


Fig. 3 - Forward Power Loss Characteristics

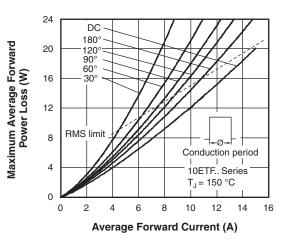


Fig. 4 - Forward Power Loss Characteristics

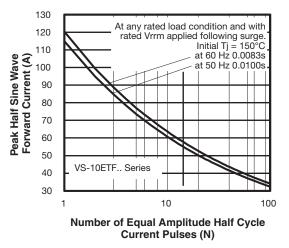


Fig. 5 - Maximum Non-Repetitive Surge Current

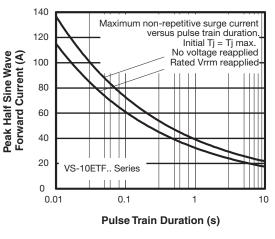


Fig. 6 - Maximum Non-Repetitive Surge Current

Revision: 18-Jun-13

3

Document Number: 94093

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

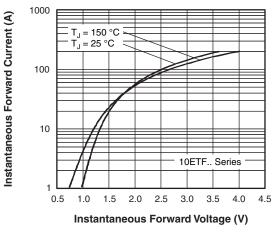


Fig. 7 - Forward Voltage Drop Characteristics

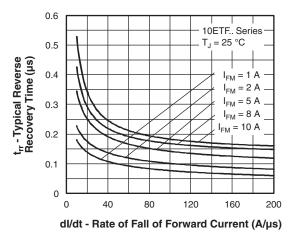


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

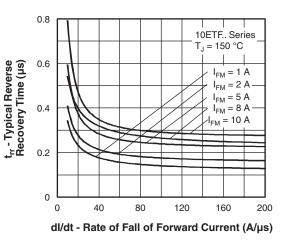
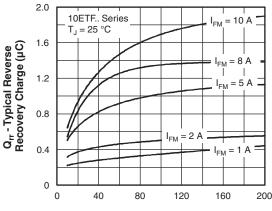


Fig. 9 - Recovery Time Characteristics, T_J = 150 $^\circ\text{C}$



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

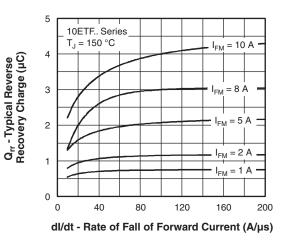
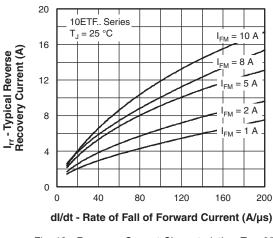


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



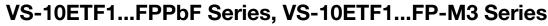


Revision: 18-Jun-13

4

Document Number: 94093

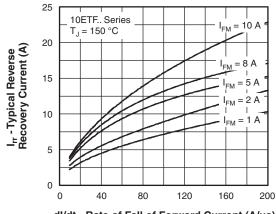
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

Vishay Semiconductors



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

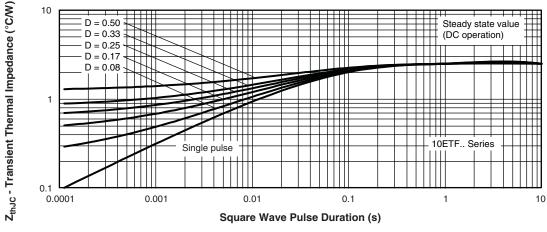


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

Revision: 18-Jun-13 5 Document Number: 94093 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	10	Е	т	F	12	FP	PbF
		2	3	4	5	6	(7)	8
	 Vishay Semiconductors product Current rating (10 = 10 A) Circuit configuration: E = Single diode Package: T = TO-220 							
	5 - 6 - 7 - 8 -	F = Vol FUI Env	tage coo _L-PAK ⁄ironmer	ft recove le x 100 ntal digit ad (Pb)-1	= V _{RRM}	1	- 04 = 4 06 = 6	

• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

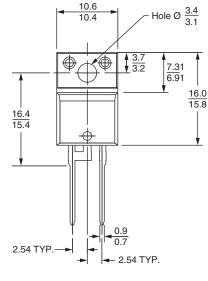
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95005			
Part marking information	TO-220 FP PbF	www.vishay.com/doc?95009			
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440			



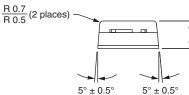
Outline Dimensions

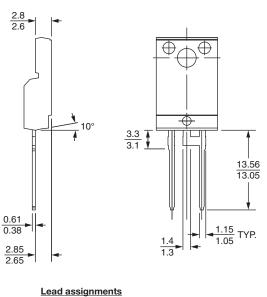
Vishay Semiconductors

DIMENSIONS in millimeters



 $\frac{4.8}{4.6}$





<u>Lead assignments</u> <u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.